

ABSTRACT OF THE DISCLOSURE

An image display device has an active matrix substrate provided with a drive circuit formed of high-performance active elements such as thin film transistors which operate with high mobility for driving
5 pixel sections arranged in a matrix configuration. The image display device has discontinuous converted regions (virtual tiles) TL formed of roughly-band-shaped-crystal silicon films in circuit sections constituting a drive circuit DDR disposed around a pixel region PAR on the active matrix substrate SUB1, and has the drive circuit DDR
10 formed of active elements such as thin film transistors fabricated in the discontinuous converted regions TL with their channel direction in a direction of growth direction of the roughly-band-shaped-crystal silicon films.